

QH8KE5

100V Nch + Nch Power MOSFET

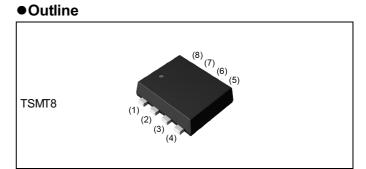
V _{DSS}	100V
R _{DS(on)} (Max.)	202mΩ
Ι _D	±2.0A
P _D	1.5W

Features

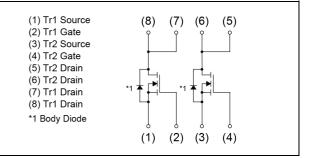
- 1) Low on resistance
- 2) Small Surface Mount Package (TSMT8)
- 3) Pb-free plating ; RoHS compliant
- 4) Halogen Free

Application

Switching Motor Drive



Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	180
Туре	Tape width (mm)	8
	Quantity (pcs)	3000
	Taping code	TCR
	Marking	KE5

● Absolute maximum ratings (T_a = 25°C ,unless otherwise specified) <Tr1 and Tr2>

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Parameter	Symbol	Value	Unit
Drain - Source voltage	V _{DSS}	100	V
Continuous drain current	I _D	±2.0	А
Pulsed drain current	I*1	±8.0	А
Gate - Source voltage	V _{GSS}	±20	V
Avalanche current, single pulse	I _{AS} *2	2.0	А
Avalanche energy, single pulse	E _{AS} *2	0.32	mJ
	P _D *3	1.5	10/
Power dissipation (total)	P _D ^{*4}	1.1	W
Junction temperature	Tj	150	°C
Operating junction and storage temperature range	T _{stg}	-55 to +150	°C

Thermal resistance

Parameter	Symbol	Values			Unit
	Symbol	Min.	Тур.	Max.	Unit
Thermal registered junction embient (total)	R_{thJA}^{*3}	-	-	83.3	°C/W
Thermal resistance, junction - ambient (total)	R_{thJA}^{*4}	-	-	113	

•Electrical characteristics (T_a = 25°C) <Tr1 and Tr2>

Parameter Symbol 0		Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 1mA	100	-	-	V
Breakdown voltage	ΔV _{(BR)DSS}	I _D = 1mA		67		mV/°C
temperature coefficient	ΔTj	referenced to 25°C	-	07	-	IIIV/ C
Zero gate voltage drain current	I _{DSS}	V _{DS} = 100V, V _{GS} = 0V	-	-	1	μA
Gate - Source leakage current	I _{GSS}	V_{GS} = ±20V, V_{DS} = 0V	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 1mA	1.0	-	2.5	V
Gate threshold voltage	$\Delta V_{GS(th)}$	I _D = 1mA		-4.0		mV/°C
temperature coefficient	Δ Τ _j	referenced to 25°C	-	-4.0	-	mv/ C
Static drain - source	D *5	V _{GS} = 10V, I _D = 2A	-	155	202	
on - state resistance	R _{DS(on)} *5	V _{GS} = 4.5V, I _D = 2A	-	210	315	mΩ
Gate resistance	R _G	-	-	2.8	-	Ω
Forward Transfer Admittance	Y _{fs} *5	V _{DS} = 5V, I _D = 2A	1.3	-	-	S

*1 Pw \leq 10µs, Duty cycle \leq 1%

*2 L \simeq 0.1mH, V_{DD} = 50V, R_G = 25\Omega, Starting T_j = 25°C Fig.3-1,3-2

- *3 Mounted on a ceramic board (30×30×0.8mm)
- *4 Mounted on a FR4 (25×25×0.8mm)
- *5 Pulsed



•Electrical characteristics ($T_a = 25^{\circ}C$) <Tr1 and Tr2>

Deremeter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Symbol Conditions		Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{GS} = 0V	-	90	-	
Output capacitance	C _{oss}	V _{DS} = 50V	-	25	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	4	-	
Turn - on delay time	t _{d(on)} *5	$V_{DD} \simeq 50V, V_{GS}$ = 10V	-	6.0	-	
Rise time	t _r *5	I _D = 1A	-	6.0	-	20
Turn - off delay time	$t_{d(off)}^{*5}$	R _L = 50Ω	-	15.0	-	ns
Fall time	t _f *5	R _G = 10Ω	-	5.0	-	

•Gate charge characteristics ($T_a = 25^{\circ}C$) <Tr1 and Tr2>

Parameter	Symbol	ymbol Conditions -		Values			Linit
Parameter	Зуший			Min.	Тур.	Max.	Unit
Total materials and	○ *5		V _{GS} = 10V	-	2.8	-	
Total gate charge	Q_g^{*5}	V _{DD} ≃ 50V		-	1.6	-	
Gate - Source charge	Q_{gs}^{*5}	I _D = 2A	V _{GS} = 4.5V	-	0.6	-	nC
Gate - Drain charge	${\sf Q}_{\sf gd}{}^{*5}$			-	0.5	-	

•Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

<Tr1 and Tr2>

Deremeter	Symbol	Conditions	Values			Unit
Farameter	Parameter Symbol Condition		Min.	Тур.	Max.	Unit
Continuous forward current	ا _S	∙ T _a = 25°C	-	-	1.25	Δ
Pulse forward current	I_{SP}^{*1}	$T_a = 25 C$	-	-	8.0	A
Forward voltage	V_{SD}^{*5}	V _{GS} = 0V, I _S = 1.25A	-	-	1.2	V
Reverse recovery time	t _{rr} *5	I _S = 2A, V _{GS} = 0V	-	28	-	ns
Reverse recovery charge	Q _{rr} *5	di/dt = 100A/µs	-	32	-	nC



•Electrical characteristic curves

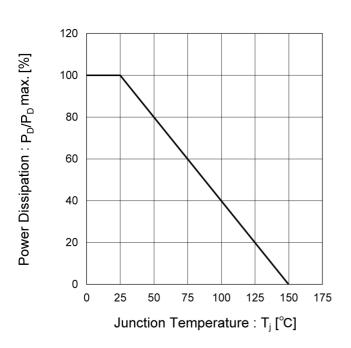
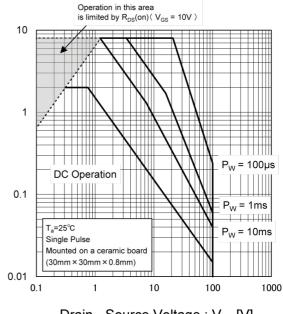


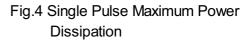
Fig.1 Power Dissipation Derating Curve

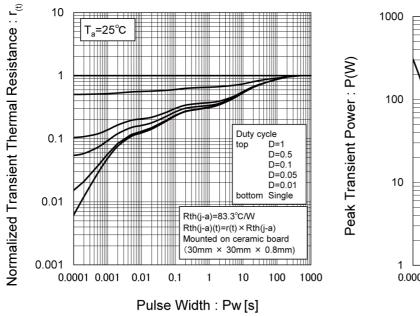
Fig.2 Maximum Safe Operating Area

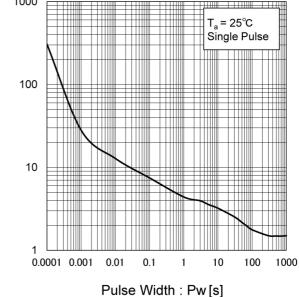


Drain - Source Voltage : V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



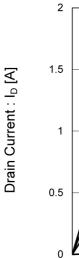




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Drain Current : I_D [A]

• Electrical characteristic curves



0 0.1

Fig.5 Typical Output Characteristics(I)

₃₅= 10V

V_{GS}= 4.5V

(_{GS}= 4.0V

T_a=25°C Pulsed

V_{GS}= 3.0V

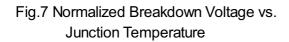
V_{GS}= 2.0V

1

Drain Current : I_D [A]

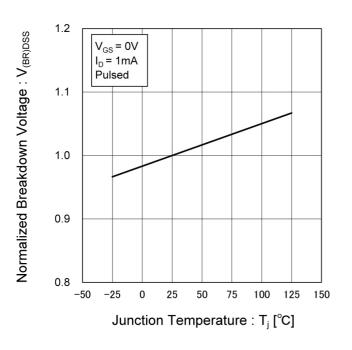
2 V_{GS}= 10V V_{GS}= 4.5V √_{GS}= 4.0V T_a=25°C 1.5 Pulsed V_{GS}= 3.0V 1 0.5 V_{GS}= 2.0V 0 2 5 6 7 3 4 9 0 1 8 10 Drain - Source Voltage : V_{DS} [V]

Fig.6 Typical Output Characteristics(II)



0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9

Drain - Source Voltage : V_{DS} [V]





• Electrical characteristic curves

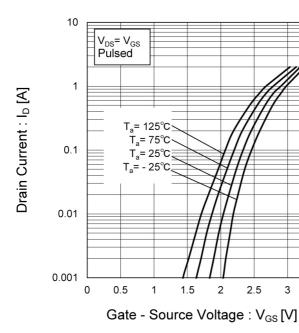


Fig.8 Typical Transfer Characteristics

Fig.9 Gate Threshold Voltage vs. Junction Temperature

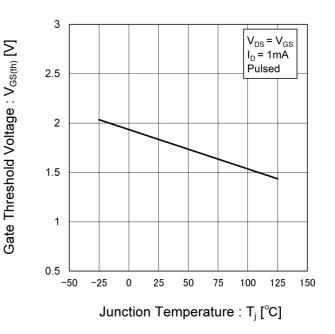
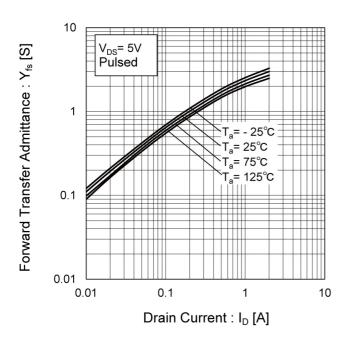


Fig.10 Forward Transfer Admittance vs. Drain Current



3.5



•Electrical characteristic curves

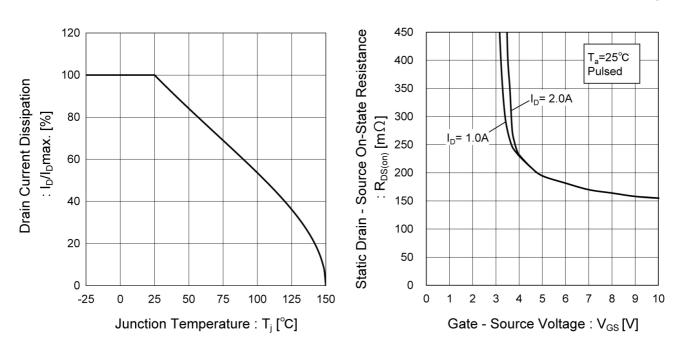
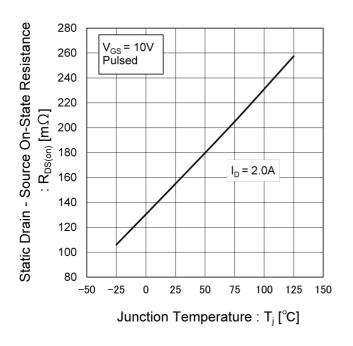


Fig.11 Drain Current Derating Curve

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature





Electrical characteristic curves

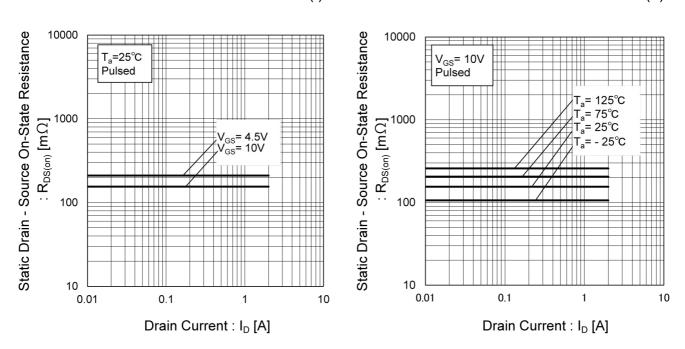
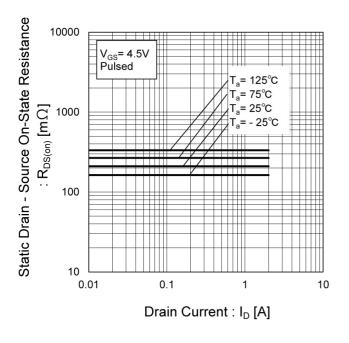


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I) Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)





• Electrical characteristic curves

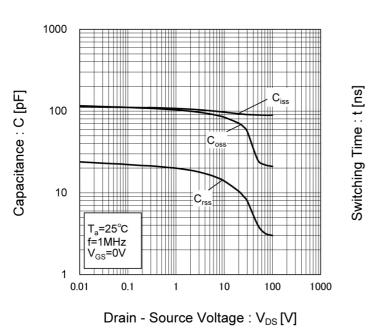


Fig.17 Typical Capacitances vs.

Drain - Source Voltage

Fig.18 Switching Characteristics

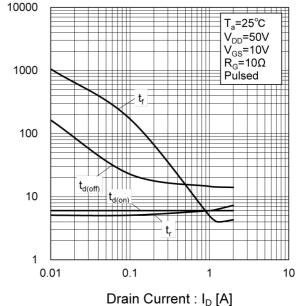


Fig.19 Typical Gate Charge

Gate - Source Voltage : V_{GS} [V]

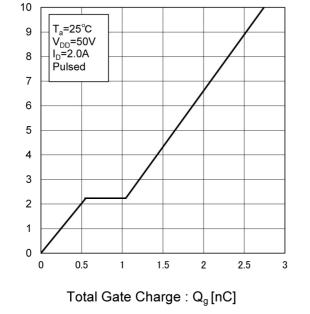
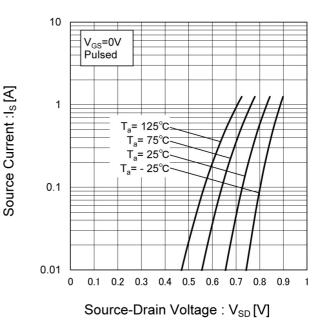


Fig.20 Source Current vs. Source Drain Voltage



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•Measurement circuits <It is the same for the Tr1 and Tr2>

Fig.1-1 Switching Time Measurement Circuit

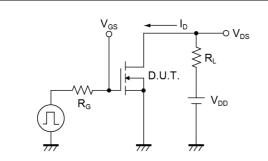


Fig.2-1 Gate Charge Measurement Circuit

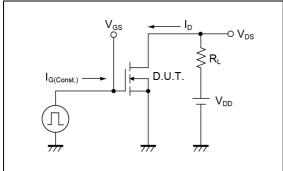


Fig.3-1 Avalanche Measurement Circuit

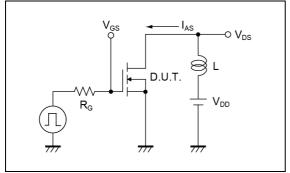


Fig.1-2 Switching Waveforms

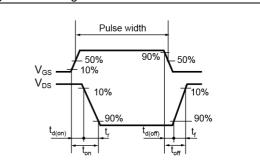


Fig.2-2 Gate Charge Waveform

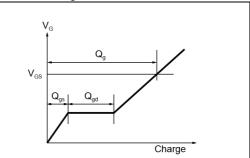
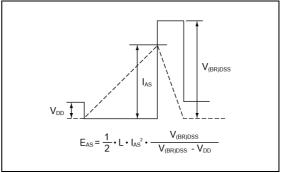


Fig.3-2 Avalanche Waveform

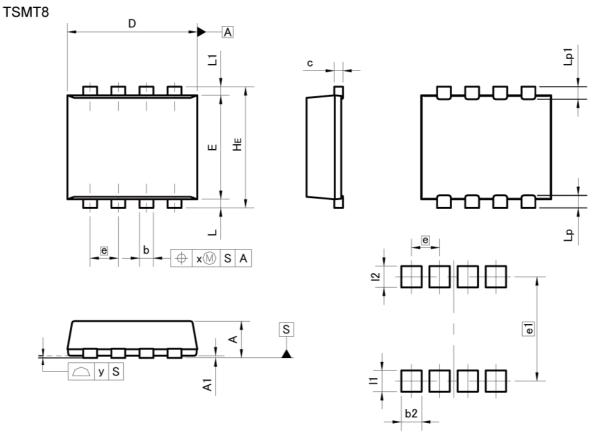


Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
А	0.75	0.85	0.030	0.033	
A1	0.00	0.05	0.000	0.002	
b	0.27	0.37	0.011	0.015	
с	0.12	0.22	0.005	0.009	
D	2.90	3.10	0.114	0.122	
E	2.30	2.50	0.091	0.098	
е	0.	65	0.026		
HE	2.70	2.90	0.106	0.114	
L	0.10	0.30	0.004	0.012	
L1	0.10	0.30	0.004	0.012	
Lp	0.19	0.39	0.007	0.015	
Lp1	0.19	0.39	0.007	0.015	
x	s 	0.10	-	0.004	
У	-	0.10		0.004	

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX MIN		MAX
b2	1	0.47	-	0.019
e1	2.41		0.0	95
1	-	0.49	-	0.019
12	-	0.49	-	0.019

Dimension in mm/inches

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Notice

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1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (^{Note 1)}, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ	CLASSII	CLASSⅢ	CLASSI

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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